

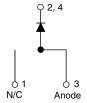
RoHS

HALOGEN

FREE

HEXFRED®, Ultrafast Soft Recovery Diode, 4 A





PRODUCT SUMMARY				
Package	TO-252AA (D-PAK)			
I _{F(AV)}	4 A			
V_{R}	600 V			
V _F at I _F	1.4 V			
t _{rr} typ.	17 ns			
T _J max.	150 °C			
Diode variation	Single die			

FEATURES

- · Ultrafast recovery time
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- · Guaranteed avalanche
- Specified at operating temperature

• Meets JESD 201 class 2 whisker test

- AEC-Q101 qualified
- ALC-Q101 quaimed
- Meets MSL level 1, per J-STD-020, LF maximum peak
- of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

DESCRIPTION / APPLICATIONS

These diodes are optimized to reduce losses and EMI / RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for freewheeling, flyback, power converters, motor drives, and other applications where high speed and reduced switching losses are design requirements.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	V_{RRM}		600	V
Maximum continuous forward current	I _{F(AV)}	T _C = 100 °C	4	
Single pulse forward current	I _{FSM}		25	Α
Repetitive peak forward current	I _{FRM}	T _C = 116 °C	16	
Maximum power dissipation	P_D	T _C = 100 °C	10	W
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +150	°C

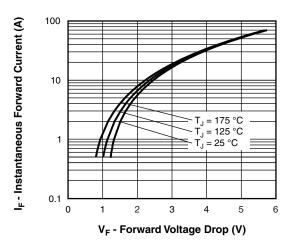




ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward voltage V _F	I _F = 4 A	-	1.5	1.8	V	
	I _F = 8 A	-	1.8	2.2		
	I _F = 4 A, T _J = 125 °C	-	1.4	1.7		
Maximum reverse I _R	V _R = V _R rated	=	0.17	3.0		
	$T_J = 125 ^{\circ}\text{C}, V_R = 0.8 \text{x} V_R \text{rated}$	=	44	300	μA	
Junction capacitance	C _T	V _R = 200 V	=	4	8	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 8.0 -		nH		

DYNAMIC RECOVERY CHARACTERISTICS (T _C = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		I _F = 1.0 A, dI _F /dt = 200 A/μA, V _R = 30 V		-	17	-	
Reverse recovery time	t _{rr}	T _J = 25 °C	$I_F = 4 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 200 \text{ V}$	-	28	42	ns
		T _J = 125 °C		-	38	57	
Deals recovery assument	I	T _J = 25 °C		-	2.9	5.2	Α
Peak recovery current	I _{RRM}	T _J = 125 °C		-	3.7	6.7	
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	40	60	nC
	Q_{rr}	T _J = 125 °C		-	70	105	
Rate of fall of recovery current dl _{(rec}	al /al+	T _J = 25 °C		-	280	=	- A/µs
	dI _{(rec)M} /dt	T _J = 125 °C		-	235	_	Ανμδ

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	150	°C
Thermal resistance, junction to case	R _{thJC}		-	-	5.0	°C/W
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	C/VV
Weight			-	2.0	-	g
vveignt			-	0.07	-	oz.
Mounting torque			6.0	_	12	kgf · cm
Wounting torque			(5.0)	_	(10)	(lbf ⋅ in)
Marking device		Case style TO-252AA (D-PAK)	HFA04SD60SH			





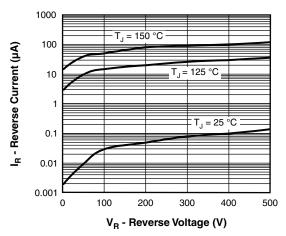


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

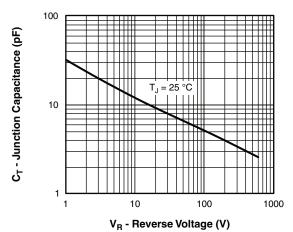


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

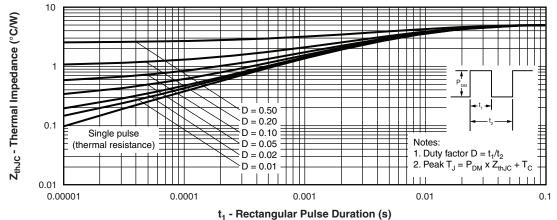


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



www.vishay.com

Vishay Semiconductors

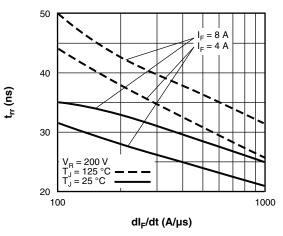


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

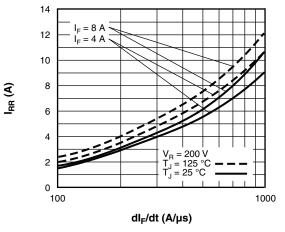


Fig. 6 - Typical Recovery Current vs. dl_F/dt

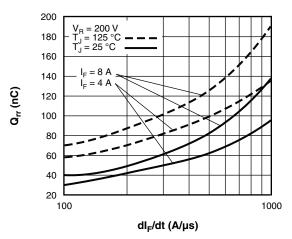


Fig. 7 - Typical Stored Charge vs. dl_F/dt

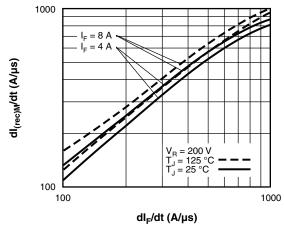


Fig. 8 - Typical dl_{(rec)M}/dt vs. dl_F/dt

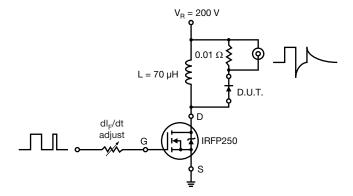
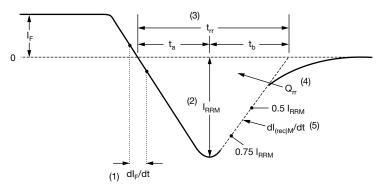


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

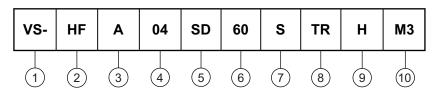
(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - HEXFRED® family

Electron irradiated

Current rating (04 = 4 A)

5 - D-PAK

Voltage rating (60 = 600 V)

7 - S = D-PAK

8 - • TR = tape and reel

• R = tape and reel (right oriented)

• L = tape and reel (left oriented)

9 - H = AEC-Q101 qualified

10 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-HFA04SD60SHM3	75	3000	Antistatic plastic tube		
VS-HFA04SD60STRHM3	2000	2000	13" diameter reel		
VS-HFA04SD60STRRHM3	3000	3000	13" diameter reel		
VS-HFA04SD60STRLHM3	3000	3000	13" diameter reel		

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95519			
Part marking information	www.vishay.com/doc?95518			
Packaging information	www.vishay.com/doc?95033			



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.